

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

**TC7MH153FK****Dual 4 - Channel Multiplexer**

The TC7MH153 is an advanced high speed CMOS DUAL 4-CHANNEL MULTIPLEXERs fabricated with silicon gate C<sub>2</sub>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

Each of these data (1C0 - 1C3, 2C0 - 2C3) is selected by the two address inputs A and B.

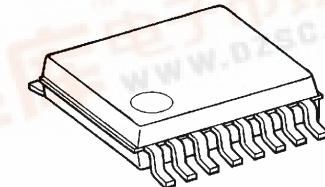
Separate strobe inputs ( $\bar{G}$ ,  $2\bar{G}$ ) are provided for each of the two four-line sections.

The strobe input ( $\bar{G}$ ) can be used to inhibit the data output; the output is fixed in low level while the strobe input is held high.

An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

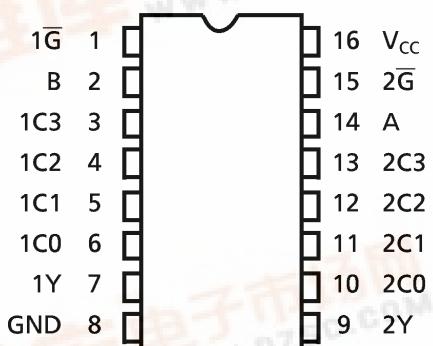
**Features:**

- High Speed..... $t_{pd} = 5.0\text{ns}(\text{typ.})$  at  $V_{CC} = 5\text{V}$
- Low Power Dissipation..... $I_{CC} = 4\mu\text{A}(\text{max})$  at  $T_a = 25^\circ\text{C}$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (min)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays..... $t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range..... $V_{CC}$  (opr) = 2V ~ 5.5V
- Pin and Function Compatible with 74ALS153



VSSOP16-P-0030-0.50

Weight: 0.02g (Typ.)

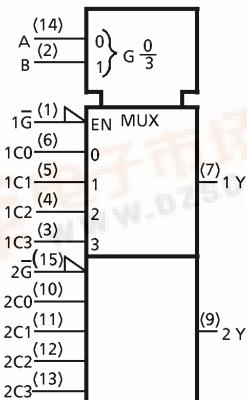
**Pin Assignment**

(TOP VIEW)

**Truth Table**

SELECT INPUTS		DATA INPUTS				STROBE	OUTPUTS
B	A	C0	C1	C2	C3	G	Y
X	X	X	X	X	X	H	L
L	L	L	X	X	X	L	L
L	L	H	X	X	X	L	H
L	H	X	L	X	X	L	L
L	H	X	H	X	X	L	H
H	L	X	X	L	X	L	L
H	L	X	X	H	X	L	H
H	H	X	X	X	L	L	L
H	H	X	X	X	H	L	H

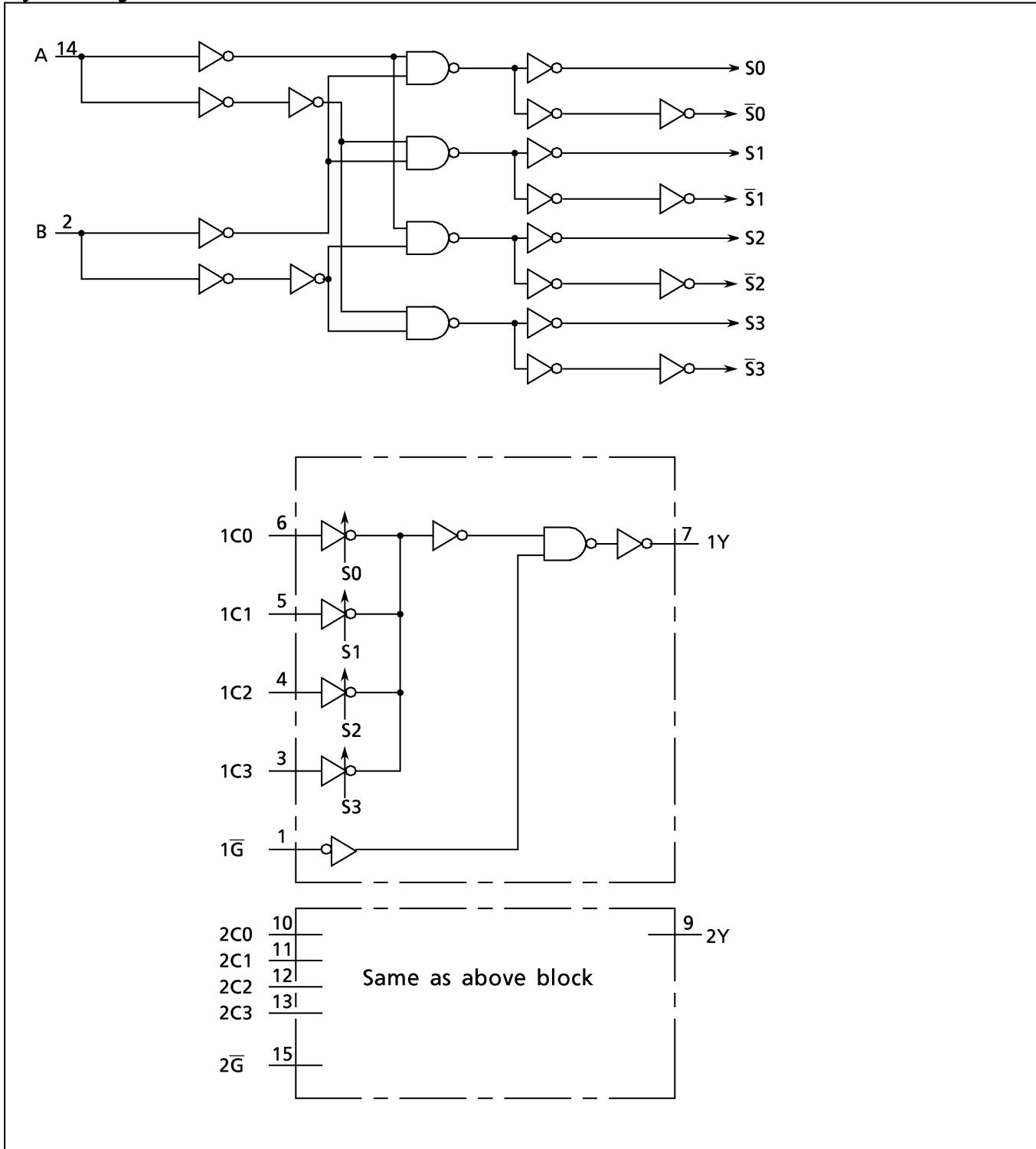
X: Don't Care

**IEC Logic Symbol**

980910EBA2

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## System Diagram



980910EBA2'

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- The information contained herein is subject to change without notice.

**Absolute Maximum Ratings**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	$V_{CC}$	-0.5~7.0	V
DC Input Voltage	$V_{IN}$	-0.5~7.0	V
DC Output Voltage	$V_{OUT}$	-0.5~ $V_{CC} + 0.5$	V
Input Diode Current	$I_{IK}$	-20	mA
Output Diode Current	$I_{OK}$	$\pm 20$	mA
DC Output Current	$I_{OUT}$	$\pm 25$	mA
DC $V_{CC}$ /Ground Current	$I_{CC}$	$\pm 50$	mA
Power Dissipation	$P_D$	180	mW
Storage Temperature	$T_{STG}$	-65~150	°C

**Recommended Operating Conditions**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	$V_{CC}$	2.0~5.5	V
Input Voltage	$V_{IN}$	0~5.5	V
Output Voltage	$V_{OUT}$	0~ $V_{CC}$	V
Operating Temperature	$T_{OPR}$	-40~85	°C
Input Rise and Fall Time	$dt/dv$	0~ 100 ( $V_{CC} = 3.3 \pm 0.3V$ ) 0~ 20 ( $V_{CC} = 5 \pm 0.5V$ )	ns/V

**DC Electrical Characteristics**

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}$ (V)	Ta = 25°C			Ta = -40~85°C		UNIT
				Min	Typ.	Max	Min	Max	
High - Level Input Voltage	$V_{IH}$		2.0 3.0~5.5	1.50 $V_{CC} \times 0.7$	—	—	1.50 $V_{CC} \times 0.7$	—	V
Low - Level Input Voltage	$V_{IL}$		2.0 3.0~5.5	—	—	0.50 $V_{CC} \times 0.3$	—	0.50 $V_{CC} \times 0.3$	V
High - Level Output Voltage	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -50\mu A$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	—	1.9 2.9 4.4	—
			$I_{OH} = -4mA$ $I_{OH} = -8mA$	3.0 4.5	2.58 3.94	—	—	2.48 3.80	—
Low - Level Output Voltage	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 50\mu A$	2.0 3.0 4.5	— 0.0 0.0	0.1 0.1 0.1	— 0.36 0.36	0.1 0.44 0.44	—
			$I_{OL} = 4mA$ $I_{OL} = 8mA$	3.0 4.5	— —	— 0.1	— 0.1	0.44 0.44	V
Input Leakage Current	$I_{IN}$	$V_{IN} = 5.5V$ or GND	0~5.5	—	—	$\pm 0.1$	—	$\pm 1.0$	$\mu A$
Quiescent Supply Current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND	5.5	—	—	4.0	—	40.0	

AC Electrical Characteristics (Input  $t_r = t_f = 3\text{ns}$ )

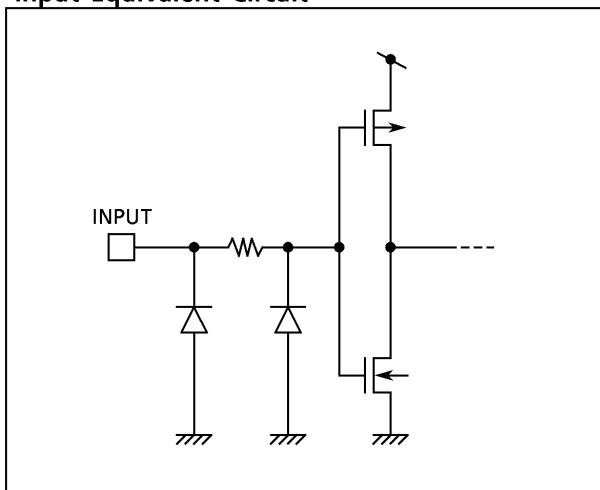
PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = -40~85°C		UNIT	
		V <sub>CC</sub> (V)	CL (pF)	Min	Typ.	Max	Min	Max		
Propagation Delay Time (C <sub>n</sub> —Y)	$t_{pLH}$ $t_{pHL}$	$3.3 \pm 0.3$	15	—	7.7	11.9	1.0	14.0	ns	
			50	—	10.2	15.4	1.0	17.5		
		$5.0 \pm 0.5$	15	—	5.0	7.7	1.0	9.0		
			50	—	6.5	9.7	1.0	11.0		
Propagation Delay Time (A,B—Y)	$t_{pLH}$ $t_{pHL}$	$3.3 \pm 0.3$	15	—	10.8	16.7	1.0	19.5	ns	
			50	—	13.3	20.2	1.0	23.0		
		$5.0 \pm 0.5$	15	—	6.8	9.9	1.0	11.5		
			50	—	8.3	11.9	1.0	13.5		
Propagation Delay Time (G—Y)	$t_{pLH}$ $t_{pHL}$	$3.3 \pm 0.3$	15	—	6.3	10.1	1.0	12.0	ns	
			50	—	8.8	13.6	1.0	15.5		
		$5.0 \pm 0.5$	15	—	4.4	6.4	1.0	7.5		
			50	—	5.9	8.4	1.0	9.5		
Input Capacitance	C <sub>IN</sub>				—	4	10	—	10	pF
Power Dissipation Capacitance	C <sub>PD</sub>	(Note 1)			—	20	—	—	—	

(Note 1): C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC(\text{opr.})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

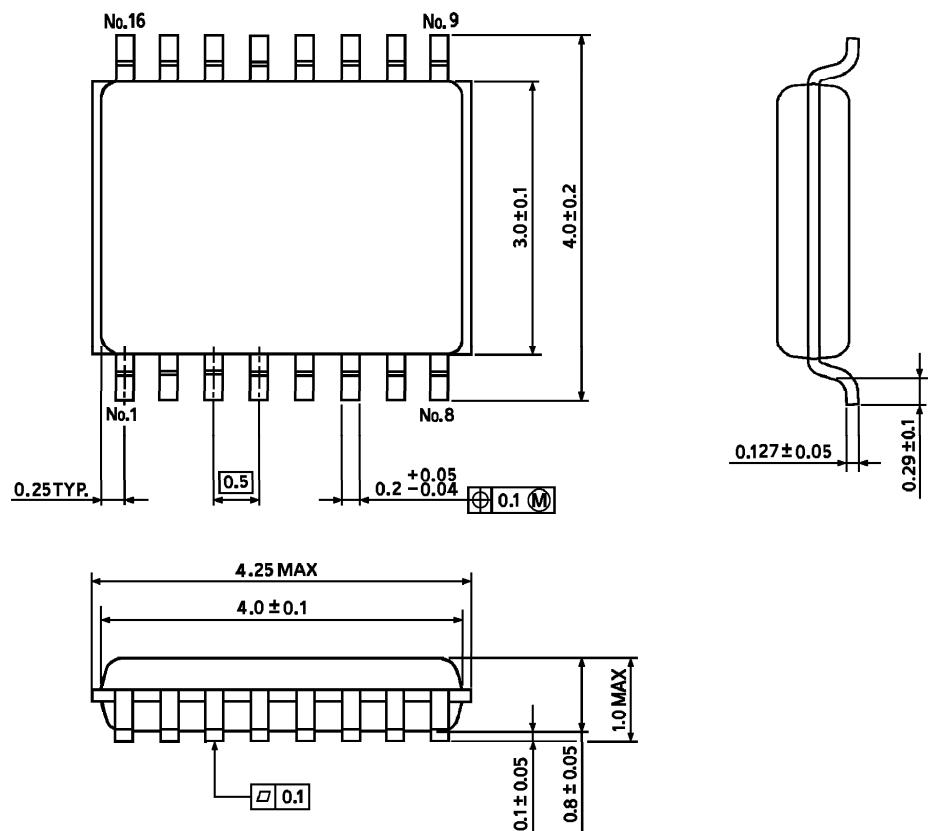
## Input Equivalent Circuit



**Outline Drawing**

VSSOP16-P-0030-0.50

Unit: mm



Weight: 0.02g (Typ.)